Amplifiers

LH0005C Operational Amplifier

General Description

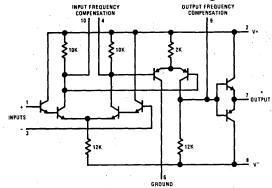
The LH0005C is a hybrid integrated circuit operational amplifier employing thick film resistors and discrete silicon semiconductors in its design. The select matching of the input pairs of transistors results in low input bias currents and a very low input offset current both of which exhibit excellent temperature tracking. In addition, the device features:

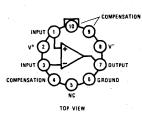
- Very high output current capability: ±40 mA into a 100 ohm load
- Low standby power dissipation: typically 60 mW at ±12V
- High input resistance: typically 2M at 25°C

- Operating range: 0° to 85°C
- Good high frequency response: unity gain at 30 MHz

With no external roll-off network, the amplifier is stable with a feedback ratio of 10 or greater. By adding a 200 pF capacitor between pins 9 and 10, and a 200 ohm resistor in series with a 75 pF capacitor from pin 4 to ground, the amplifier is stable to unity gain. The unity gain loop phase margin with the above compensation is typically 70 degrees. With a gain of 10 and no compensation the loop phase margin is typically 50 degrees.

Schematic and Connection Diagrams

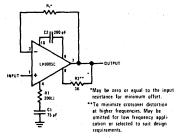




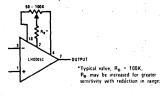
Order Number LH0005CH See Package H10D

Typical Applications

Voltage Follower

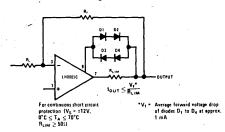


Offset Balancing Circuit

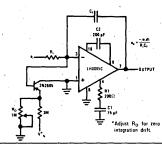


*Previously called NH0005C

External Current Limiting



Integrator With Bias Current Compensation



Absolute Maximum Ratings

Supply Voltage
Power Dissipation (see Curve)
Differential Input Voltage
Input Voltage
Peak Load Current
Storage Temperature Range
Operating Temperature Range
Lead Temperature (soldering, 10 sec)

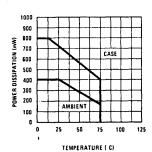
±20V 400 mW ±15V Equal to supply voltages ±100 mA -55°C to +125°C 0°C to 85°C 300°C

Electrical Characteristics

PARAMETER	CONDITIONS	LH0005C			
		MIN	TYP	MAX	UNITS
			(Note 2)		
Input Offset Voltage	$R_S \le 100 \Omega$		3	10	mV
Input Offset Current			5	25	nΑ
Input Bias Current			20	100	nA .
Large Signal Voltage Gain	$R_L = 10K, R2 = 3K, V_{OUT} = \pm 5V$	2	5		V/mV
Output Voltage Swing	$R_{L} = 10 \text{k}\Omega$ $R_{L} = 100\Omega$	-10 -4	±6	+6 +4	V V
Input Resistance	$T_A = 25^{\circ}C$	0.5	2		МΩ
Common Mode Rejection Ratio	$V_{IN} = \pm 4V, R_S \le 100 \Omega, T_A = 25^{\circ}C$	50	60		dB
Power Supply Rejection Ratio	T _A = 25°C	50	60		dB [.]
Supply Current (+)			3	5	mA
Supply Current (~)			2	4	mA

Note 1: These specifications apply for pin 6 grounded, $V_S = \pm 12V$, with Resistor R1 = 200Ω in series with Capacitor C1 = 75 pF from pin 4 to ground, and C2 = 200 pF between pins 9 and 10, over the temperature range of 0° C to $\pm 85^{\circ}$ C unless otherwise specified.

Note 2: Typical values are for 25°C only.



Maximum Power Dissipation